25 mm (1") encapsulated photomultiplier 9110V15 series data sheet



1 description

The 9110V15 encapsulated photomultiplier comprises a 25mm (1") diameter, compact, rugged, end window photomultiplier with a plano-concave window, high temperature blue-green sensitive bialkali photocathode and 10 BeCu dynodes of circular focused design.

The photomultiplier is encapsulated, together with a voltage divider, in a mumetal* sleeve.

This type will operate up to 175°C and has a minimum plateau length of 100 V at 175°C.

2 applications

- oil well logging including measuring while drilling (MWD)
- x-ray and gamma ray spectroscopy
 in harsh environments

3 features

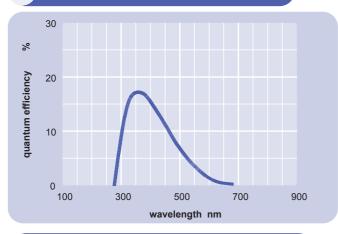
- rugged
- high temperature operation
- encapsulated in a mu-metal sleeve with an integral voltage divider

4 window characteristics

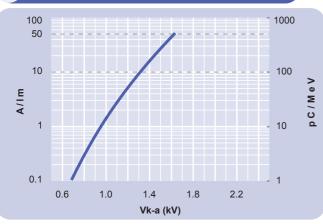
spectral range* (nm) refractive index (n _d)	280 - 630 1.49
K (ppm) Th (ppb) U (ppb)	300 250 100

* wavelength range over which quantum effifiency exceeds 1 % of peak

typical spectral response curves



6 typical voltage gain characteristics



7 characteristics

photocathode: high temperature bialkali active diameter quantum efficiency at peak luminous sensitivity	mm % µA/lm		22 17 50	
with CB filter with CR filter	ľ	4	6 5	
dynodes: 10CFBeCu				
anode sensitivity: nominal anode sensitivity max. rated anode sensitivity overall voltage for nominal A/Im overall voltage for max. rated A/Im gain at nominal A/Im dark current at 20 °C:	A/lm A/lm V V x 10 ⁶		10 50 1350 1650 0.2	1600
DC at nominal A/Im	nA		0.1	1
DC at max. rated A/Im	nA		0.5	
pulsed linearity (-5 % deviation): divider A	mA		20	
resolution:				
¹³⁷ Cs with 1.0 " dia x 1.5 " NaI(TI)	a. a1		10	
temperature coefficient:	% °C ⁻¹		-0.5	
timing: multi-electron rise time multi-electron fwhm single electron rise time transit time weight:	ns ns ns ns		2 4 1.8 15 64	
maximum ratings: anode current	μA			100
cathode current gain sensitivity	nA x 10 ⁶ A/lm			20 1 50
temperature V (k-a) ¹⁾ V (k-d1) V (d-d) ²⁾ ambient pressure (absolute)	pC/MeV °C V V kPa	-55		500 175 2300 450 300 202

subject to not exceeding max. rated sensitivity subject to not exceeding max rated V(k-a)

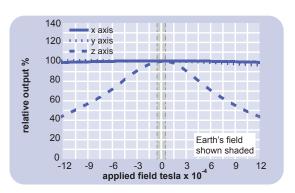
qualification shock & vibration levels (all 3 axes, non-operating)

random vibration:	
5 Hz to 100 Hz roll on	6 dB/octave
50 Hz to 500 Hz	0.89 q ² /Hz
500 Hz to 1000 Hz roll off	6 dB/octave
composite	25 g rms
duration	60 mins/axis
sine vibration:	
amplitude	30 g peak
frequency range	50 Hz to 2000 Hz
sweep rate	2 octaves/min
duration	60 mins/axis
shock (half sine wave):	
0.5 ms duration	1000 g peak
4 ms duration	250 g peak
shocks per axis	3 up, 3 down

microphony under random vibration (all 3 axes, operating)

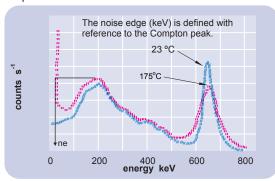
random vibration:	
20 to 100 Hz roll on	6 dB/octave
100 to 400 Hz	0.103 g ² /Hz
400 to 500 Hz roll off	6 dB/octave
composite	6.5 g rms
duration	5 mins/axis
microphony at 100 pC/MeV above a	
threshold of 5.5 pC (55 keV)	< 1 cps

8 magnetic field sensitivity



9 pulse height resolution with NaI(TI) crystal

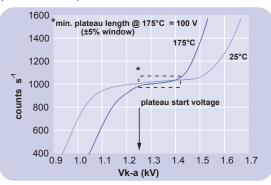
This pmt is tested for resolution at room temperature & at high temperature.



output data		typ 20	0 °C max	175 °C typ
operating voltage for 13 pC/MeV operating voltage for 100 pC/MeV pulse height resolution noise edge	V V % keV	1050 1350 10 <10	1300 1600	1200 1500 14 35

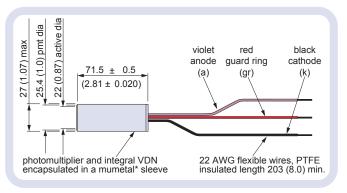
10 pulse counting with NaI(TI) crystal

Pulse counting plateau with 137 Cs and Nal(TI) crystal (1.0" dia. x 1.5")

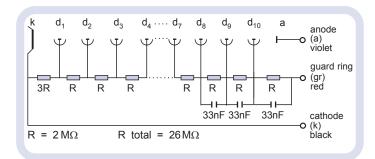


plateau data				max
combined 25 °C / 175 °C: plateau start (1.5 pC threshold) plateau length ±5 %	V V	100	1250	1500

11 external dimensions in mm (inches)



12 voltage divider distribution

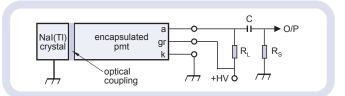


13 ordering information

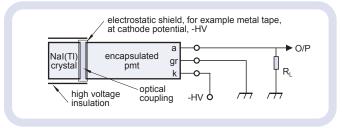
The 9110V15 meets the specification contained in this data sheet. For different specifications please then discuss your requirements with us. For customer specific requirements, **ET Enterprises** will change the 2 digit numeric suffix to indicate additional tests and selection.

14 applications with Nal(TI) crystals

The use with positive HV is recommended, as shown in the diagram below:



With negative HV, as shown in the next diagram, any material in contact with the window, for example the Nal(TI) crystal, **must** be maintained at cathode potential and insulated for safety. The interface between the Nal(TI) crystal and the pmt window **must** be shielded along the body of the housing.



These precautions are essential to prevent erratic behaviour.

*mumetal is a registered trademark of Magnetic Shield Corporation

ET Enterprises Limited 45 Riverside Way Uxbridge UB8 2YF United Kingdom tel: +44 (0) 1895 200880

tel: +44 (0) 1895 200880 toll free: (800) 399 4557 fax: +44 (0) 1895 270873 fax: (325) 235 2872 e-mail: sales@et-enterprises.com web site: www.et-enterprises.com web site: www.electrontubes.com

ADIT Electron Tubes 300 Crane Street Sweetwater TX 79556 USA tel: (325) 235 1418 toll free: (800) 399 4557 fax: (325) 235 2872 e-mail: sales@electrontubes.com

choose accessories for this pmt on our website

an ISO 9001 and ISO 14001 registered company

The company reserves the right to modify these designs and specifications without notice. Developmental devices are intended for evaluation and no obligation is assumed for future manufacture. While every effort is made to ensure accuracy of published information the company cannot be held responsible for errors or consequences arising therefrom.

